"Soft" Alkali Bromide and Iodide Fluxes for Crystal Growth

Vladislav V. Klepov,* Christian A. Juillerat, Kristen A. Pace, Gregory Morrison, and Hans-Conrad zur Loye*

Department of Chemistry and Biochemistry
University of South Carolina, Columbia, SC, 29208, USA
*Corresponding authors: <u>zurloye@mailbox.sc.edu</u>; klepov@mailbox.sc.edu

Abstract

In this review we discuss general trends in the use of alkali bromide and iodide (ABI) fluxes for exploratory crystal growth. The ABI fluxes are ionic solution fluxes at moderate to high temperatures, $207 - \sim 1300$ °C, which offer a good degree of flexibility in the selection of the temperature profile and solubility. Although their main use is to dissolve and recrystallize "soft" species such as chalcogenides, many compositions with "hard" anions, including oxides and nitrides, have been obtained from the ABI fluxes, highlighting their unique versatility. ABI fluxes can serve to provide a reaction and crystallization medium for different types of starting materials, mostly the elemental and binary compounds. As the use of alkali halide fluxes creates an excess of the alkali cations, these fluxes are often reactive, incorporating one of its components to the final compositions, although some examples of non-reactive ABI fluxes are known.

Keywords: flux crystal growth, alkali halide fluxes, chalcogenides, single crystals, inorganic synthesis

Introduction

Crystal growth from solution rests on the well-known principle of supersaturation that can be controlled by many factors, such as the solvent nature, polarity, temperature, competing compounds present in the solution, etc. All these parameters can be finely optimized to achieve the formation of good quality crystals, which are necessary for the structural characterization via single crystal X-ray diffraction of a new compound. ¹ Solution crystal growth in different organic solvents works well for most organic compounds; however, crystallization of non-ionic extended structures is more challenging and a far less understood process. While ionic compounds and complexes can be easily recrystallized from a polar solvent, such as water or acetonitrile, at room or slightly elevated temperature, more covalent extended structures can only be obtained under conditions when the system has enough energy to overcome the energetic barriers related to breaking and recombination of covalent bonds. Although water can still be employed for crystallization at high temperatures (and often is), preventing water evaporation from a reaction vessel becomes increasingly difficult above ~220-230 °C, a temperature at which polytetrafluoroethylene (PTFE) softens and standard hydrothermal techniques can no longer be used. Beyond this temperature, a much more sophisticated apparatus has to be used to be able to use water and other common solvents as a reaction media.²

A convenient alternative to conventional solvents is various inorganic compounds that melt at readily achievable temperatures without reaching their boiling points during the reaction, circumventing the necessity of having expensive closed reaction vessels that can withstand high pressures. One well-known example of a high temperature flux is MoO₃, which has been widely used for crystallizing various phases, for example, uranium oxides. ³ This compound melts at 795 °C, creating a reaction and crystallization medium for the starting materials, and can be slowly evaporated to promote the formation of large single crystals by slow oversaturation of the solution. Another major benefit of using fluxes for crystal growth is the ability to assume a kinetic control over a reaction. High temperature solid state reactions are often carried out at temperatures above 600 °C to achieve sufficient diffusion rates. A downside of using high temperatures is the inevitable formation of thermodynamic stable products commonly observed with rather simple binary or ternary compositions. ¹ The use of a flux allows for circumventing this limitation as a molten, liquid flux component significantly improves diffusion rates of a reaction by solubilizing the starting materials and therefore products can be obtained at lower temperatures and shorter

reaction times. This offers an additional degree of control of the reaction conditions, paving a path toward kinetic products.

There are a number of excellent reviews devoted to flux crystal growth in general, ^{1,4,5} the use of selected fluxes, ^{6,7} and materials that can be obtained using fluxes. ⁸ Chloride fluxes are among the most universal and widely applied fluxes, and have been extensively used for crystallization of oxides, chalcogenides, and chlorides. ⁴ Their heavier counterparts, bromide and iodide fluxes, have attracted much less attention, although they offer a wider reaction temperature range. In this review, we focused on alkali bromide and iodide (ABI) fluxes to summarize and rationalize their application in exploratory crystal growth. We show their application to different systems to reveal most often used approaches and highlight possible future directions in the development of the alkali bromide and iodide flux technique.

General Considerations

The most important factor that governs processes during flux crystal growth is supersaturation. Ideally, once the starting materials dissolved in a flux at a peak temperature, the supersaturation is reached when the concentration of the products exceeds their solubility upon decreasing temperature. After crossing the saturation limit, the melt becomes oversaturated and the nucleation process, which usually takes place on the reaction vessel walls or flux surface, occur more rapidly than nuclei dissolution, resulting in some of the nuclei reaching their critical size to become seed crystals that initiate crystal growth process. According to the classical view on crystal growth, the size of the crystals is a function of how fast the oversaturation occurs, the growth of larger crystals is promoted by slower oversaturation, which favor growth process over the nucleation one, while the opposite result, a large number of smaller crystals, can be achieved by rapid oversaturation of the melt. Although there are two dominating factors that affect the rate at which the melt is oversaturated, temperature profile and the nature of the flux, other factors, such as crucible size and material, have been recently realized as having a great impact on the products of a flux reaction and will be discussed in more details in the following sections.

Starting Materials. In order to successfully carry out a flux reaction one must carefully select appropriate starting materials, a flux component, a reaction vessel, and a temperature profile. The starting reagents are most commonly considered first since they largely control the composition of the target product, a flux must be then chosen to dissolve the chosen reactants, a

reaction vessel must be chosen that will successfully contain the flux, and lastly a temperature profile must be picked that supports all three of the previous choices.

There are several common approaches to choosing starting materials which include recrystallizing a polycrystalline precursor, reaction of the elements, and binary reagents, although starting material selection is oftentimes a matter of reagent availability. Often, a polycrystalline sample of the desired product (precursor) can be obtained easily by other methods, typically by solid state methods, and then recrystallized in a flux to obtain a single crystalline product. ¹⁰ In this approach, the choice of flux is essential, as the flux should dissolve the starting material in order to aid in the crystallization; however, the flux must not form stable compounds with the components of the precursor, which is often difficult to achieve since the solvent must break the covalent bonds of the precursor. It is hard to predict which flux will be suitable for this role, especially for alkali halide fluxes, as they contain alkali metal cations that readily incorporate into the final products. More often, different fluxes are probed for suitability for a certain system, as it happens with selection of an organic solvent for organic systems.

Other approaches use fluxes both as a reactant and crystallization medium at the same time. One such approach involves the use of elements as starting materials and has proved useful for the precise control over the reaction composition in a closed system. The downside of using some of the elements is their volatility and difficulties with handling hazardous substances. For example, the use of chlorine or bromine is rather limited in closed systems, such as evacuated fused silica tubes, while chloride/bromide fluxes can offer a safe and convenient source of chlorine/bromine. 11-¹⁴ Sulfur is another example and has been used in the elemental form in many reactions, although it has a boiling point of ~445 °C and builds up pressure beyond this temperature, potentially resulting in tube bursting. To prevent this, longer ramping times are required which allow the starting materials to react with each other, forming non-volatile species. This disadvantage can be overcome by using binary compounds, which circumvents the use of elemental sulfur and reduces the reaction time without a significant risk of tube bursting. The use of binaries is especially efficient for exploratory crystal growth as it offers fast screening of phase space and identification of stable compositions. The downside of using the binary compounds is the occasional difficulty of obtaining binary phases that are not commercially available or binary starting reagents that contain unexpected impurities that alter the outcome of the reaction, with product formation depending on the reagent's lot. ¹⁵ For example, rare earth sulfides are not currently commercially

available, except for lanthanum sulfide, and require additional experiments to obtain the pure starting materials. ¹⁶

Recrystallization of materials that were obtained via the solid state route and reactions between elements or binaries are by far the most popular reactions employing fluxes. There are some interesting approaches that are not widely employed, but offer an alternative way of synthesis, which sometimes can save a lot of efforts. For example, Guo, Huang, and coworkers use oxides accompanied by elemental sulfur and elemental boron to obtain sulfide phases. ¹⁷ Boron has a high affinity for oxygen, attacking oxides to form B_2O_3 that causes the reaction, which is accompanied by the reduction of sulfur to sulfide, to form a sulfide *in situ*. Coupled with a flux that promotes the reaction and then crystal growth, this approach offers a convenient way for exploratory crystal growth as it allows for using oxides, which usually are more readily available than sulfides or the elements. Another approach is oxidative elimination in the presence of NaI/CsI flux that has recently been employed by Kovnir et al. ¹⁸ In this reaction, CuI was used as an oxidizer to create an oxidized boron phosphide Na₂BP₂ according to the reaction Na₃BP₂ + CuI \rightarrow Na₂BP₂ + CuI \rightarrow Na₂BP₂ + CuI \rightarrow Na₂BP₂ + CuI \rightarrow Na₂BP₂ to form a desired species.

Unlike a solid state reaction, which offers the final product in, ideally, pure form at the end of a reaction, flux crystal growth involves one crucial step after the reaction is done – separation of residual flux from the products. For ABI fluxes, most of the common polar solvents serve this purpose well. Although water is the most common choice to dissolve a flux, most of the products obtained via ABI flux crystal growth are air- or moisture-sensitive, which requires the use of anhydrous organic solvents, such as methanol, ethanol, or DMF. These solvents offer a relatively fast, within hours, removal of a residual flux, with little damage to moisture sensitive crystals. Additional precautions should be taken with air sensitive crystals, and properly degassed and dehydrated solvents should be used.

Reaction Vessels. Compatibility between the reaction vessel and the flux is among the most important criteria for choosing a reaction vessel. While ABI fluxes are largely compatible with almost any reaction vessel of choice, using a mixed flux that includes a fluoride component will limit the available choices, as fluorides tend to extensively attack fused silica and alumina reaction vessels. Although fluoride fluxes are incompatible with alumina, small amounts of metal

fluorides can be tolerated without debilitating damage to the vessel. Some of the syntheses reported for ABI fluxes use metal fluoride starting materials, specifically Schleid's work, and carbon coating the tube, or containing the reaction in an alumina crucible or gold ampule and using the fused silica as secondary containment proved successful in protecting the fused silica tube from the small amount of metal fluoride. Although ABI fluxes are generally considered compatible with fused silica tubes, there are reports on using a bromide flux in a fused silica tube that resulted in Si incorporation from the tube. ¹⁹ This can be limited by the use of carbon coating, or a secondary container.

Other important factors for choosing reaction vessels are the desired atmosphere, the melting point, and in some cases the surface to volume ratios. Reaction vessels open to atmosphere, for example alumina and platinum crucibles, are primarily used for oxide synthesis, as targeted synthesis of halide, chalcogenide, and pnictide products often limit the amount of oxygen available to the reaction. Evacuated and sealed fused silica and Pyrex tubes can be used for closed systems, where fused silica has a much higher melting point and is more frequently used than Pyrex. The synthesis of the reported chalcogenides, oxychalcogenides, and pnictides, are almost exclusively carried out in evacuated fused silica tubes to exercise control over the incorporation of oxygen. In contrast, many different reaction vessels were used for halide containing products, including open alumina and platinum reaction vessels and sealed fused silica tubes. Additionally, several reported syntheses used He arc-sealed tantalum or niobium ampules. Although not discussed in any ABI flux papers, the surface area to volume ratio of the reaction vessels has been found to play a significant role in alkali chloride/fluoride flux reactions and could be important to consider in further studies using ABI fluxes. ²⁰

Temperature Profiles. For crystal growth to occur, a solution must be sufficiently supersaturated to facilitate nucleation. In molten solutions, it is important to select a flux that is capable of dissolving the reactants and has a substantial change in solubility over the temperature range of interest, otherwise, the nucleated crystals will be re-dissolved and no single crystals will form. The optimal rate of nucleation occurs over a given temperature range which is specific to each system, thus exploratory crystal growth largely focuses on this determination (Figure 1). ^{3,4}

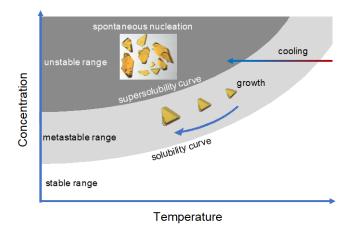


Figure 1. A simplistic representation of crystallization process using solutions. After melting a sufficient amount of starting materials at high temperature (top right corner), the reaction is slowly cooled to achieve a supersaturated solution and promote crystal growth.

Indeed, selecting an appropriate reaction temperature is among the most critical considerations to make when conducting crystal growth experiments. ABI fluxes offer a great deal of versatility when it comes to accessible temperature ranges, and have generally been used over a wide temperature range from approximately 400-1000°C. The melting points of the ABI fluxes and some selected eutectics are listed in Table 1. An extremely helpful tool in flux selection is the FactSage thermochemical database, which offers a large number of binary salt phase diagrams with the compositions and melting points of eutectic mixtures^{21–23} Figure 2 shows the temperature ranges used most frequently for the compounds discussed in this review, and demonstrates that reactions involving ABI fluxes have typically been carried out at temperatures 50-200°C higher than the melting point of the flux. There are many examples that indicate a significant influence of the reaction temperature on the resulting crystal morphology; for example, lower temperatures may produce irregularly-shaped crystals while increasing temperature may favor more defined morphologies.

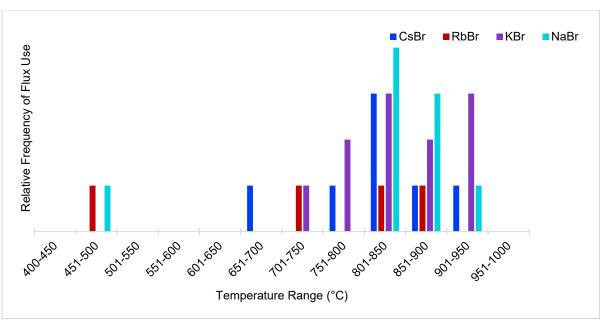
Table 1. Melting point of alkali bromide and iodide fluxes and some eutectics with low melting points

Salt	m.p., °C	Salt	m.p., °C	Mixtures, molar ratio	m.p., °C
LiBr	552	LiI	469	CsI/LiI (34:66)	~207
NaBr	747	NaI	661	KI/LiI (63:37)	~286
KBr	734	KI	681	CsBr/LiBr(37:63)	~281
RbBr	693	RbI	642	NaI/CsI (49:51)	~420

CsBr	636	CsI	621	CsBr/NaBr (58:42)	~458
------	-----	-----	-----	-------------------	------

One important feature of alkali iodide fluxes is their ability to build up pressure of iodine upon heating to high temperatures. This feature can be illustrated by a recent report by McQueen et al., in which solid state incorporation of CsCl, CsBr, and CsI into Cu₅O₂(PO₄)₂ was carried out to achieve the formation of the (CsX)Cu₅O₂(PO₄)₂ (X= Cl, Br, and I) salt inclusion phases. ²⁴ While CsCl and CsBr can be obtained by quenching a solid state reaction between the respective alkali halide salt and Cu₅O₂(PO₄)₂, the iodide analogue was obtained by slow cooling to equilibrate the iodine vapors with the sample. The presence of water vapor can increase the amount of iodine formed via the reaction: CsI + H₂O \rightarrow CsOH + HI, with subsequent decomposition of HI to the elements. ²⁵ Considerable work has been carried out to study the thermal behavior of CsI due to the presence of radioactive iodine and cesium, present as CsI in nuclear reactors. ²⁵

There has also been a wide range of reaction dwelling times reported for ABI fluxes, ranging from no dwell to dwell periods of up to five weeks. In general, there does not seem to be much correlation between the flux used and the selected dwell times, though in many cases, increasing dwell times results in larger crystals. Similarly, cooling rates of approximately 1-20°C per hour over a range of about 200-500°C below the dwell temperature have been identified as suitable slow-cooling periods, although many of the discussed compounds were prepared with no slow-cooling, thus it is not clear whether or not this is a necessary step in every synthesis. It is also worth noting that several of the synthetic procedures used to prepare the compounds discussed in this review include a multi-step temperature profile, in which the initial synthesis step involves slowly ramping to a given temperature and possibly dwelling at that temperature for some time, followed by quickly heating to the reaction temperature. This is a useful technique for reactions which contain reagents prone to decomposition or those which require a reaction of the starting materials prior to dissolving the reagents in the flux; for example, the decomposition of NH4H2PO4 into a P2O5 flux or the pre-reaction of elemental sulfur or selenium with other reagents present in the reaction.



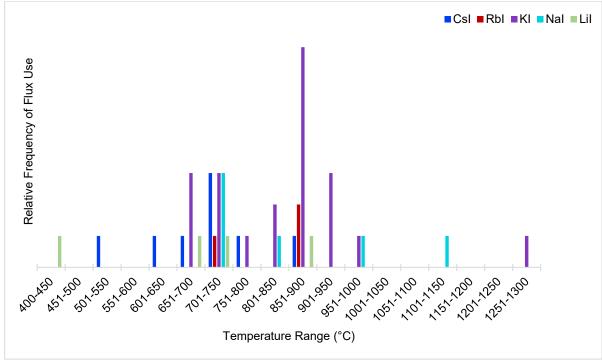


Figure 2. Flux temperature ranges that have been used to obtain the compounds discussed in this review.

Materials Obtained Using ABI Fluxes.

By far the most numerous materials obtained from ABI fluxes are chalcogenides and oxychalcogenides, which comprise almost 50% of all phases (Figure 3). One of the main reasons

for that is the suitability of the soft Pearson bases, bromide and iodide, to dissolve and provide a reaction medium for "soft" chalcogenides, whereas "harder" fluoride and chloride fluxes are more suitable for the oxide systems. There is however no strict boundary between the application of both types of fluxes and sometimes they can be used interchangeably. Another reason is that many research groups, once they found suitability of a certain flux for a system, tend to apply the same flux to all similar systems, which can also result in preference of some fluxes over other, although it does not necessarily mean that these phases could not be obtained by other fluxes.

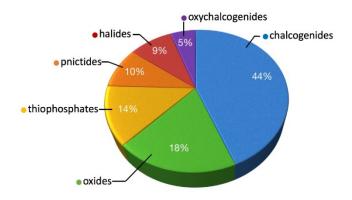


Figure 3. An approximate distribution of the phases obtained using ABI fluxes.

Oxides

The ABI fluxes have proved successful for the exploratory crystal growth of new complex oxides, where the bromides have received more attention compared to the iodides. In addition to exploratory crystal growth, the ABI fluxes have been used to recrystallize polycrystalline powders, control crystal morphology, and control structure compositions. The reactions generally consist of reacting the appropriate oxides, and in some cases the metal salts, with the ABI containing flux and heating the mixture to between 600 and 900 °C for times ranging from a few hours to several days. CsBr was the most frequent flux used in oxide synthesis; in addition, several mixed fluxes were used including KCl/KI, NaBr/KBr, NaBr/CsBr, KI/KNO₃, and the very complex NH₄Cl/AlF₃/NaCl/KBr/H₃BO₃ mixture.

CsBr has been extensively used as a flux by the Schleid group for the single crystal growth and structure determination of several families of rare earth selenates and silicates, namely MF(SeO₃) (M = Sc, Y, Ho- Lu), Ho₃(SeO₃)₄, Sc₂O₂(SeO₃), Er₃F(SiO)₄(SeO₃)₂, and Pr₅(SiO₄)₂(SeO₃)₃.²⁶⁻³⁵ The MF(SeO₃) family features an unusual pentagonal bipyramidal

coordination environment for the rare earth cation. Generally, the respective rare earth sesquioxide, rare earth fluoride, and SeO₂ were mixed in a 1:1:3 ratio with an excess amount of CsBr and heated in a carbon coated silica ampule at 700-850 °C for 5-7 days. In the case of the silicates, the silica tube reaction vessel acts as the SiO₂ source due to the reactive nature of fluorides towards the silica. Schleid used alumina crucibles or gold ampules contained within the silica tubes to protect the tube from the reactive fluoride.

The ABI fluxes have also been used to control the crystal morphology of several oxides such as NaNd(MoO₄)₂,³⁶ KEu(MoO₄)₂,³⁷ Li₂NiPO₄F,³⁸ and NaNbO₃.³⁹ In each case the identity of the flux or the amount of flux played a significant role in the crystal morphology. For KEu(MoO₄)₂, stoichiometric amounts of K₂CO₃, Eu₂O₃, and MoO₃ were mixed with excess amounts of KCl or KBr flux and heated at 700-850 °C for 2-6 h in an alumina crucible. As the temperature increases, the morphology of the isolated crystals changes from undefined to rod-like and ultimately to octahedral. Reactions at 750 °C were determined to be best for rod shaped crystals and longer dwell times produced larger crystal sizes, while KBr was preferred over KCl, as it produced crystals more uniform in size.³⁷

Similarly, in the synthesis of NaNd(MoO₄)₂, the bromide flux resulted in a smaller distribution of crystal sizes. Crystals of NaNd(MoO₄)₂ were obtained with mixing Na₂CO₃, Nd₂O₃, and MoO₃ in stoichiometric amounts and adding excess amounts of NaCl or NaBr flux and heating the mixture in an alumina crucible at 750-900 °C for 10 mins to 6 h. In addition to the flux identity, the temperature and dwell time were important variables for control over the morphology of the crystals. Using a lower dwell temperature of 750 °C produced crystals with no defined morphology, and as the temperature was increased more defined octahedral crystals were obtained. Larger crystals can be obtained with longer dwell times, and the enhanced size of the crystals resulted in an increase of the emission peaks of the luminescent compound.³⁶

Crystals of Li₂NiPO₄F were grown from mixtures of LiCO₃, NiO, NH₄H₂PO₄ that were preheated at 400 °C for 3h before adding LiF and excess KCl/KI flux and heating the mixture to 600 °C for 1 h. The morphology of the Li₂NiPO₄F crystals was sensitive to the ratio of the preheated reactants and to the amount of KCl/KI flux (Figure 4). By increasing the amount of the flux, the morphology of the crystals changed from undefined to faceted, to rectangularly shaped, to one dimensional rods.³⁸

A variety of fluxes were used for the synthesis of NaNbO₃ in order to determine the influence on particle size and morphology as well as photocatalytic activity. Out of the fluxes used (Na₂SO₄, NaF, NaCl, and NaBr), NaBr produced the largest particles the surface area of the particles was nearly twice as large as the next leading flux; however, photocatalytic activity was much higher in particles grown using Na₂SO₄.³⁹

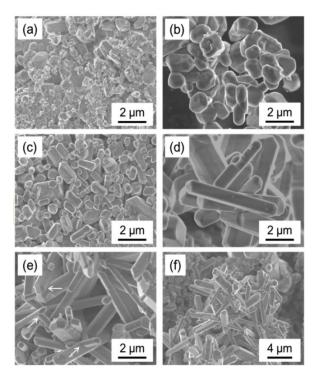


Figure 4. SEM images of Li₂NiPO₄F grown from KCl-KI fluxes showing the progression of crystal morphology as the mol % of reactants to flux decreases a) 100 , b) 80, c) 50, d) 20, and e) 10 mol %. f) lower magnification image of (e). Reproduced from Yamada, T.; Zettsu, N.; Kim, H.-m.; Hagano, Y.; Handa, N.; Yubuta, K.; Teshima, K., One-Dimensional Growth of Li₂NiPO₄F Single Crystals from Intermediate LiNiPO₄ Crystal Surface Using KCl–KI Fluxes, *Cryst. Growth Des.* **2018**, *18*, 6777-6785 with permission of American Chemical Society.³⁸

The successful synthesis of Sr₃MgSi₂O₈:Eu²⁺ was also dependent on the ratio of the flux components. Sr₃MgSi₂O₈:Eu²⁺ made by mixing SrCO₃, MgO, SiO₂, and Eu₂O₃ with varying ratios of a four or five component flux including, NH₄Cl, AlF₃, NaCl, KBr, and H₃BO₃. Multiple ratios were attempted to find favorable conditions for the doping of Eu²⁺, and also the best conditions for maximized luminescence. The authors concluded that changing the concentrations of NH₄Cl and H₃BO₃ greatly influenced the luminescence of the products, where increasing NH₄Cl seemed to improve luminescence efficiency, while increasing the amount of H₃BO₃ had a negative impact on the efficiency; the relative amounts of NaCl and KBr did not play a significant role.⁴⁰

The identity of the alkali halide flux was also used to control the doping of the alkali cation, and thus the oxidation of Mn, in Na and K doped LaMnO3. For both Na and K doped LaMnO3 systems, La₂O₃ and MnCO₃ were added to the desired flux (ACl, ABr, or AI) and heated at 900, 850, or 750 °C, respectively. In both systems, the doping of the alkali cation was most extensive in the AI flux, i.e. La_{0.85}Na_{0.14}MnO_{2.97} (NaCl, 900 °C), La_{0.88}Na_{0.12}Mn_{0.96}Na_{0.04}O₃ (NaBr, 850 °C), and La_{0.84}Na_{0.16}Mn_{0.93}Na_{0.07}O₃ (NaI, 750 °C) and La_{0.85}K_{0.08}MnO_{2.93} (KCl, 900 °C), La_{0.89}K_{0.07}MnO_{2.99} (KBr, 800 °C), and La_{0.88}K_{0.10}Mn_{0.98}O₃ (KI, 750 °C). In the Na system, a small amount of Na was also doped on the Mn site if NaBr or NaI were used. In the K system, the more extensive doping of the K in the case of using a KI flux leads to a higher symmetry structure type. No discussion was given on how temperature influences the incorporation of Na or K, although different temperatures were chosen for the different fluxes.

In the study of the crystal growth of MgFe₂O₄, MgAl₂O₄, and MgCr₂O₄ the identity of the chosen flux was determined to have significant effects on the yield of the reaction. MgFe₂O₄, MgAl₂O₄, and MgCr₂O₄ can be synthesized by mixing MgO and the corresponding M₂O₃ with excess NaBr or KBr and heating in a platinum crucible. While both fluxes were effective at producing the desired product, using LiF or LiCl resulted in a higher yield as compared to NaBr and KBr. ⁴³ ABI fluxes are also useful for recrystallizing powder products obtained from traditional solid state routes in order to obtain single crystals large enough for single crystal structure determination. For example, both Cs₂V₄O₉ and Rb₂V₃O₈ crystals were obtained in this manner using a CsBr or RbBr flux. Crystals of Cs₂V₄O₉ were grown by carrying out the solid state reaction with CsVO₃ and V₂O₃ in a sealed Pyrex tube at 550 °C for 10 h, followed by mixing the resulting powder with a large excess of CsBr in a fused silica tube and heating at 700 °C before slow cooling at 6 °C/h to 470 °C. ⁴⁴ The crystal growth of Rb₂V₃O₈ was carried out in a similar manner, where stoichiometric ratios of RbVO₃, V₂O₃, and V₂O₅ are mixed and heated at 550 °C overnight in a sealed tube, then the resulting powder is added to excess RbBr flux and heated in a sealed fused silica tube to 750 °C and slowly cooled to 500 °C at 6 °C/h. ⁴⁴

A number of complex metal oxides have been obtained from ABI fluxes, where the ABI flux plays an important role of providing alkali cations that incorporate into the final structure. Crystals of Cs₂Cu₃P₄O₁₀ were grown from CuO, P₂O₅, and CsI flux in an evacuated fused silica tube heated at 700 °C for 2 days followed by slow cooling to 300 °C at 6 °C/h. ⁴⁵ Similarly, NaCuAsO₄ was grown from the combination of As₂O₅, CuO, CuBr₂, and Cs₂O in an excess of

eutectic NaBr/CsBr flux. Carbon coated silica ampules were used as the reaction vessel and heated to 300 °C for one day, then 650 °C for 4 days followed by slow cooling to 450 °C at 2.5 °C/h. ⁴⁶ To obtain crystals of Ba₂K₂Te₂O₉, Ba(H₄TeO₆) was added in a 1:5 weight ratio with KNO₃/KI flux and heated in a platinum crucible to 500 °C, held for four days, and slow cooled to room temperature in 12 h. ⁴⁷ The layered oxide, Na_{0.27}CoO₂, can be prepared by mixing CaC₂O₄·2H₂O with ten times excess NaI and heating in an alumina crucible at 750 °C for 24 h. ⁴⁸ Lastly, Cs₃(UO₂)₂(PO₄)O₂ can be obtained by loading a platinum crucible with (UO₂)₃(PO₄)₂(H₂O)₄ and CsI flux and heating to 750 °C for 10 h followed by slow cooling at 7 °C/h to room temperature. The unique 3D framework contains larger pores filled with Cs cations. ⁴⁹ On the contrary, the synthesis of Bi₂(Sr_{1-x}Ca_x)₃Cu₂Oy gives an example of an unreactive flux. This composition was obtained from dissolving stoichiometric ratios of Bi, Sr, Ca, and Cu nitrates in water and heating up to 500 °C and dwelling for 20h before adding 75% be weight KBr flux and heating in a platinum crucible at 3 h followed by heating to 850 or 880 °C and slow cooling to 700 °C at 1°C/h. ⁵⁰

Halides/Oxyhalides

There are about half as many halide containing phases grown from ABI fluxes as compared to oxide phases and the structures of the halide containing phases are highly varied and include simple binary phases, perovskite related, high order extended structures, and organic containing extended structures. As compared to the oxides, whose syntheses had a wide variety of mixed fluxes reported, almost all the oxyhalides are grown from single component melts.

Among the reported binary phases are Hf_{0.86}I₃ and TaBr_{2.94}.^{51, 52} Black rod-shaped crystals of Hf_{0.86}I₃ were produced by reducing HfI₄ with aluminum at 850 °C in the presence of NaI flux contained in a sealed tantalum vessel and held for 16 days before slow cooling to room temperature at 5 °C/h. The structure is composed of hexagonal close packed layers of iodide ions where 5.16 out of the 6 octahedral holes are filled by Hf ions.⁵² TaBr_{2.94} completes the five-member family of binary tantalum bromides TaBr₅, TaBr₄, Ta₆Br₁₅, and Ta₆B₁₄; the TaBr_{2.94} structure is distantly related to the perovskite structure type. TaBr_{2.94} was obtained by the reduction of TaBr₅ with the wall of the tantalum reaction vessel at 500 °C with NaBr or RbBr flux. ⁵¹

The ternary phases include Cs₂AuBr₆, Cs₂AuI₆, Y₁₆Br₂₄Ir₄, and the derivatives of the Ba₇F₁₂Cl₂ structure. Single crystals of the distorted perovskites, Cs₂AuBr₆ and Cs₂AuI₆, were obtained from slow heating mixtures of Au, Br₂ or I₂, and CsI in alumina crucibles sealed inside

fused silica tubes at 630 and 550 °C, respectively over 42 h and dwelling for 10 h. After heating, the reactions were cooled at 5 °C/h. ⁵³ Y₁₆Br₂₄Ir₄ was obtained in a good yield using Ir metal, YBr₃, and a RbI or KI flux and heating in a sealed Nb tube at 900 °C for 5 weeks. ⁵⁴ Ba_{6.668}Ca_{0.332}F₁₂Br₂ and the Ba₇-xCa_xF₁₂(Cl_yBr_{1-y})₂ family both adopt the Ba₇F₁₂Cl₂ structure and were obtained from the appropriate alkaline earth halides and a NaBr or NaCl/NBr flux, respectively. The reactions were contained in covered platinum reaction vessels and heated to 900 °C and cooled to 600 °C in 3 h. ⁵⁵

Further examples demonstrating the versatility of ABI fluxes include the novel lithium europium and strontium carbodiimides, LiSr₂(NCN)I₃, LiEu₂(NCN)I₃ and LiEu₄(NCN)₃I₃, which resulted from a reaction of EuI₂, NaCN, NaN₃, and LiI.⁵⁶ The reactions were contained in sealed tantalum ampules within sealed fused silica tubes and heated to 880 °C (or 700 °C for LiEu₄(NCN)₃I₃) for 3 days and cooled at 6 °C/min to room temperature. Both Eu containing compositions were obtained using the same ratio of reactants and the product identity was controlled by adjusting the temperature.⁵⁶ The presence of divalent europium in the structure was confirmed by magnetic measurements, with effective magnetic moments of 8.00(7) and 7.65(5) μ_B per Eu, respectively, within the expected range of magnetic moments for Eu²⁺. LiSr₂(NCN)I₃ features a unique extended structure with empty tetrahedral Sr₄ entities. ⁵⁷ Crystals of the M₆N₃S₄Br of (M = La – Nd) compounds were grown from oxidizing the rare earth metal with sulfur and NaN₃ with the corresponding MBr₃ in the presence of a NaBr flux. The reactions were heated at 850 °C for 7 days in evacuated silica tubes. ⁵⁸

The reported synthetic conditions for obtaining halides, so far, have not used any metal oxide starting materials, but rather used metals in their elemental forms, likely to prevent the inclusion of O in the resulting structures. Two of the three oxyhalides use oxide precursors, while the oxygen source for ((C₂)₂O₂Dy₁₄)I₂₄ is not discussed. La₃OBr(AsO₃)₂ was synthesized from heating stoichiometric mixtures of NH₄H₂AsO₄, NH₄Br, and La₂O₃ in platinum crucibles at 500 °C for 6h and 850 °C for 60 h before adding 20 equivalents of NaBr/KBr flux and heating at 900 °C for 72 h and slow cooling at 10 °C/h to room temperature. ¹⁴ In the synthesis of the oxyhalide, CsSm₂₁(SeO₃)₂₄Br₁₆, SmOBr and SeO₂, were reacted in a CsBr flux and heated at 797 °C and slow cooled to 570 K at 5 °C/h. ¹³. Crystals of the oxyhalide, ((C₂)₂O₂Dy₁₄)I₂₄ were synthesized from DyI₃, Dy powder, graphite powder, and NaI flux using a He-arc sealed tantalum reaction vessel heated at 1000 °C for 10 days; however, the source of O in the structure was not discussed. ⁵⁹

Chalcogenides

Binaries. ABI fluxes were employed to synthesize or recrystallize several binary chalcogenide compounds. In order to obtain new, non-linear optical materials, Guo et al. performed a reaction between Ga₂O₃, S, and B at 950 °C.⁶⁰ In the absence of a flux, the reaction resulted in monoclinic Ga₂S₃, whereas the addition of KI flux favored the formation of a cubic polymorph. Both compounds show a good Second Harmonic Generation (SHG) response and an exceptional laser induced damage threshold (LIDT). These two reactions are good examples of how a flux can divert a reaction pathway and lead to a different product, emphasizing the importance of new flux applications to known systems to discover new phases.

The application of different fluxes and the use of different flux to reagent ratios can also help fine tune the particle size of binary chalcogenides. For example, ZnS:Cu, Al phosphor particle sizes can be optimized by controlling the identity and the amount of the flux. ⁶¹ Interestingly, fluxes like NaCl and CaCl₂ facilitate a fast initial particle growth followed by virtually no further size increase with time, whereas CsCl, KCl, KI, and NaI fluxes behaved in a similar way except they promoted a secondary particle growth step after the plateau time. Another example of a flux controlled particle size synthesis is growth of CoS₂ particles in KCl, KBr, and KI fluxes (Figure 5).⁶² In the absence of a flux, the reaction between stoichiometric amounts of Co and S resulted in particles with an irregular morphology, while the flux reactions resulted in faceted, polyhedral particles. Among the three fluxes, the KCl flux was found to provide the most uniform sized polyhedra.

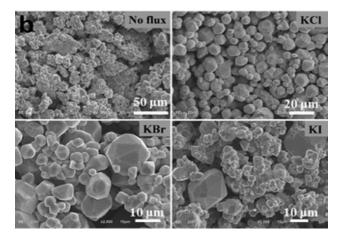


Figure 5. The influence of different fluxes on the size and shape of CoS₂ particles. Reproduced from Wang, Y.; Wu, J.; Tang, Y.; Lü, X.; Yang, C.; Qin, M.; Huang, F.; Li, X.; Zhang, X., Phase-controlled synthesis of cobalt sulfides for lithium ion batteries., *ACS Appl Mater Interfaces* **2012**, *4*, 4246-4250.⁶² with permission of American Chemical Society.

Large single crystals of PdS for electrical transport property measurements were grown from a KI flux.⁶³ A powder sample of PdS was initially obtained by reacting stoichiometric quantities of the elements at 900 °C and then recrystallized from a 20-fold excess of KI at the same temperature, demonstrating the ability of the KI flux to dissolve sulfide materials. The same flux has been used to obtain single crystals of PrS₂ at a temperature of 700 °C, slightly above the flux melting point of 681 °C.⁶⁴ A KBr flux allowed for the crystallization of SmTe_{1.80} single crystals from a mixture of the elements; however, no efforts were made to improve upon the relatively low 5% yield of the phase.⁶⁵ As a final example, it was determined that SnS could be recrystallized as a single phase from a KI flux at 740 °C. ⁶⁶

Mixed chalcogenides. The ABI fluxes can offer a convenient reaction media to obtain mixed chalcogenide phases, such as Nd₂S₂Te, Dy₄S₄Te₃, CsTb₃STe₄, and CsTb₅S₂Te₆. The latter two compounds were crystallized from a CsBr flux at 850 °C via the oxidation of Tb metal with S and Te. At the same temperature, the direct reaction of Nd, Se, and Te in a stoichiometric ratio resulted in Nd₂S₂Te powder, which can be recrystallized in an equimolar amount of CsBr flux. A ternary mixed chalcogenide phase Dy₄Se₄Te₃ has been obtained starting with Dy₂O₃ and B as a reducing agent in a KI flux. A similar composition with very similar unit cell metrics, Dy₄S₄Te_{2.3}, was obtained by the reaction between Dy₂S₃, Dy₂Te₃, and Te.

Ternaries. A number of ternary phases have been obtained from the ABI fluxes. For example, colorless single crystals of Li₃AsS₃ were grown from a LiI flux starting with the elements. Although the melting point of LiI is about 469 °C, the crystals were successfully grown at 450 °C, indicating a possible reaction between the flux and the starting materials led to a melting point lowering of the flux. A reactive NaBr flux at 950 °C was used to produce single crystals of NaIn₃S₅ from CaS and In₂S₃.⁶⁷ In this reaction the flux provides both a reaction medium and functions as the Na⁺ source. Another antimony ternary chalcogenide, Ni₂SbTe₂, was obtained by reacting stoichiometric ratios of the elements in a KI flux at 900 °C. ⁶⁸ The same reaction in the absence of the flux resulted in a product with the same composition, however in the form of smaller single crystals. Schleid et al. reported on the synthesis of the ternary tellurides RbSc₅Te₈, KYTe₂, and RbYTe₂ that were prepared using KBr and RbBr as reactive fluxes at 900 °C.^{69,70} A study on the crystal growth of photoluminescent Pb₂P₂S₆ in KI at 800 °C and LiBr/KBr at 500 °C fluxes revealed different particle morphologies of the final products as a function of the flux used. This

serves as a good illustration of how different flux choices (and reaction temperatures) can be used to tune particle size and optical properties of the resulting material.

There are several lanthanide chalcogenide systems that were explored using ABI fluxes, ⁷¹ and the synthesis of new *f*-element chalcogenides tends to attract a lot of attention because of their interesting structural features and magnetic and optical properties. ⁸ For example, the structures of Gd₃Cu₂Te₇ and U₂Cu_{0.78}Te₆, which were both isolated from a KI flux at 850 °C, contain linear Te-Te chains (Figure 6), a common structural motif in chalcogenide chemistry. ⁷² Numerous compositions can be obtained from ABI fluxes, for example, a large family of lanthanide copper sulfides, *Ln*CuQ₂ (*Ln* = lanthanides, Q = S, Se), was synthesized using several different flux systems. Successful crystal growth in this system was achieved with CsCl, KBr, and KI fluxes, ^{73–75} where, interestingly, KBr and KI are interchangeable for the recrystallization of *Ln*CuSe₂ (La, Ce, Pr, Nd, and Sm). ⁷⁵ An isotypic series of composition RbLnSe₂ was prepared from a RbI flux using an excess of Rb₂S₃, which potentially also functioned as an auxiliary flux. Most *f*-elements are magnetic and due to the localized nature of the 4*f* electrons, RbCeSe₂, RbTbSe₂, and RbErSe₂ exhibit simple paramagnetic behavior with no apparent magnetic interaction between the lanthanide cations. A Curie-Weiss law fit for RbCeSe₂ shows a large negative Weiss constant, which was attributed to crystal-field splitting of the ²F_{5/2} Ce(III) ground state. ⁷⁶

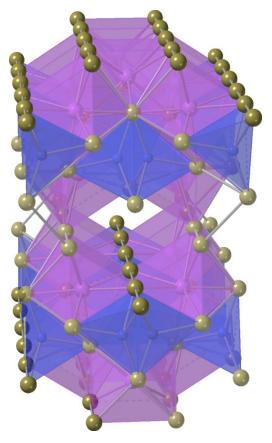


Figure 6. A fragment of Gd₃Cu₂Te₇ structure showing linear Te-Te-Te chains.⁷² Tellurium, gadolinium, and copper are shown in brown, blue, and magenta, respectively.

The ABI fluxes allow for the synthesis of compounds containing both 3d and 4f elements as well as interlanthanide phases, which can result in interesting physical properties due to interactions between the metal cations. For example, a series of compounds Ln₃TSe₆ (Ln = Sm, Gd; T = In, Cr) and Tb₃CrSe₆ were obtained by reacting stoichiometric quantities of the elements in a KBr flux at 850 °C.⁷⁷ The products exhibit magnetic properties and magnetic measurements on Gd₃CrSe₆ revealed a sharp drop in the magnetic susceptibility below 10(1) K, indicative of an antiferromagnetic transition. No such drop in the susceptibility was observed for the analogous Sm₃CrSe₆ and Tb₃CrSe₆ compositions, suggesting that the ordering originates from the Gd³⁺ cations. Related mixed 4f element chalcogenides, Er₃Sm Q_6 (Q = S, Se) and Er_{1.12}Sm_{0.88}Se₃, were grown from a KI flux.⁷⁸ Although the structures of Er₃Sm Q_6 (Q = S, Se) exhibit minimal Er/Sm disorder as they are found in different coordination environments with coordination numbers of 6 and 7 for Er and 8 for Sm, it is difficult to precisely quantify the amount of disorder as their X-ray scattering is very similar.

Quaternaries. The ABI fluxes often provide alkali cations that incorporate into the final products, thus playing the role of a reactive flux. This incorporation favors more complex compositions that usually result in more complex crystal structures. A number of noncentrosymmetric quaternary chalcogenide phases have been reported and were investigated for their non-linear optical properties. For example, by exploiting the lone pair effect of Sb³⁺ to induce noncentrosymmetry, La₂CuSbS₅ was synthesized in a mixed CsBr/BaCl₂ flux at 900 °C.⁷⁹ This compound exhibits a reasonable SHG response (0.5×AgGaS₂) with a large LIDT (6.7×AgGaS₂). Another couple of NLO active sulfides, Ba₄CuGa₅ Q_{12} (Q = S, Se), were grown from a KBr flux at 750 °C,80 and their SHG response demonstrated that the sulfide compound is a promising NLO material in infrared region. Further improvements of the optical characteristics were observed in Ba₁₀Zn₇ M_6Q_{26} (M = In, Ga; Q = S, Se) that were obtained by a reaction of the elements in a KBr/CsBr flux confined in a graphite crucible at 1000 °C.81 Similarly, single crystals of Ba₆Zn₆ZrS₁₄ were grown by the direct combination of the elements in the presence of a KI flux at 900 °C.82 The product mixture contained Ba₂ZnS₃ as a side product, and optimization of the solid state reaction condition was able to yield a phase pure sample starting from the elements. The product is stable against water exposure and exhibits good photoluminescent properties that make it a possible candidate for optical applications.

Quaternary lanthanide chalcogenides have been studied extensively for their magnetic properties and several series of compounds have been crystallized out of ABI fluxes. Ibers et al. prepared KLn₂CuS₄ (Ln = Y, Nd, Sm, Tb, Ho) and K₂Ln₄Cu₄S₉ (Ln = Dy, Ho) by the reactive flux method using K₂S and KI to aid crystal growth at 700 °C. ⁸³ All compounds can also be obtained in the absence of KI, however with significantly lower yields. Magnetic measurements performed on K₂Ho₄Cu₄S₉ showed a paramagnetic behavior with a magnetic moment that agrees well with the theoretical value of 10.60 μ _B for Ho³⁺. Two other copper-containing phases, SrCuCeSe₃ and SrCuPrSe₃, were obtained from CsI flux at 800 °C.⁸⁴ Despite the very similar sizes of the lanthanide cations in these two compounds, they adopt distinct structure types.

The use of a KBr/BaBr₂ mixed flux enables Ba incorporation into the final product as can be illustrated by the synthesis of the quaternary chalcogenides Ba $LnMQ_3$ (Ln = lanthanide, M = Cu, Ag, Au, Q = Se or Te). ⁸⁵ The Ln and M elements along with BaQ were mixed with a KBr/BaBr₂

flux and reacted at 850 °C. The flux-assisted reactions yielded single crystals in 35–65% yield with minor quantities of Ln_2Q_3 impurities, while only binaries of Ln/Te formed in similar reactions without a flux. Inverse magnetic susceptibility data for BaNdAgTe₃ were fitted to a Curie-Weiss law, and exhibit no magnetic transitions down to 5 K. In a similar way, Ba₄Nd₂Cd₃Se₁₀ and Ba₄ Ln_2 Cd₃S₁₀ (Ln = Sm, Gd, Tb) were formed from a BaBr₂/KBr flux at 900 °C.⁸⁶ The reciprocal magnetic susceptibility of the Tb-containing compound was fit to the Curie-Weiss law and resulted in an effective magnetic moment of 9.94 μ B, which is consistent with the theoretical value of 9.72 μ B.

The KBr flux offers a convenient way to synthesize pentanary KCaEr₂CuS₅, providing both solution for crystal growth and the K⁺ cation that incorporates into the structure.⁸⁷ Initially, a mixture of Er₂S₃, CaS, Cu, and S were employed as starting materials. However, while optimizing the reaction conditions it was determined that an optimal yield is obtained when Cu₂S is used instead of a mixture of the elements. The compound exhibits paramagnetic behavior down to 5 K and an estimated bandgap of 2.4 eV measured by UV-vis spectroscopy.

Thiophosphates and thiosilicates. The ABI fluxes have been used to prepare several families of thiophosphate compounds. Isostructural K_{0.5}Ag_{0.5}Nb₂PS₁₀ and Rb_{0.38}Ag_{0.5}Nb₂PS₁₀ were grown from the elements in eutectic AgI/KI and AgI/RbI fluxes, respectively, at 800 °C.88,89 Similarly, KBr and CsBr fluxes at 950 °C were used to obtain $Rb_3Ln_3[PS_4]_4$ (Ln = Pr, Er) and $Cs_3Pr_5[PS_4]_6$. $^{90, 91}$ Crystal growth of rare earth sulfides $NaLnP_2S_6$ (Ln = La and Ce) and $CsLnP_2S_7$ (Ln = Pr, Nd, Sm, Gd, Tb, Dy, Ho, Er, Yb, and Y) was facilitated by a CsI/NaI flux at 500 °C.16 The synthesis of the NaLnP₂S₆ compounds is preceded by reduction of the P(V) containing P₂S₅ P starting material to P(IV) in P₂S₆⁴. Possible reducing agents for this reaction are iodide and sulfide anions, although it is unclear which anion contributes more. Magnetic susceptibility measurements revealed paramagnetic behavior of all compounds and the effective moments derived from Curie-Weiss law fits are in a good agreement with the expected theoretical values. In a similar way, uranium thiophosphates were grown from eutectic CsI/NaI and RbI/NaI fluxes from US2, Na2S, and P₂S₅ binaries at temperatures between 500 to 750 °C.⁹² All compounds exhibit rather complex $Rb_5Na_3[U(PS_4)_4],$ compositions, $Cs_5Na_6[U(PS_4)_4](PS_4)$, $CsNa[U(PS_4)_2]$ $Cs_{1.67}Na_{0.52}I_{0.19}[U(PS_4)_2]$, $Cs_{1.033}Na_{1.343}I_{0.376}[U(PS_4)_2]$, and $Rb_{1.35}Na_{0.93}I_{0.28}[U(PS_4)_2]$, structures. Magnetic susceptibility data for CsNa[U(PS₄)₂] indicate the transition from one

paramagnetic state to another at 200-225 K, which is not accompanied with a structural change and is likely due to an electronic phenomenon.

There are several thiosilicates that were obtained from ABI fluxes. The serendipitous crystal growth of NaY₃S₃[SiS₄] occurred when Be, Y, and S were reacted in an excess of a NaBr flux inside an evacuated silica tube, which served as a source of Si.⁹³ The reaction was then optimized by using SiS₂ as a starting material in the same NaBr flux at 850 °C, which resulted in a water- and air-resistant product in an approximate yield of 80%. Uranium(IV) thiosilicates Cs₂Na₄[U₂(SiS₄)₂(Si₂S₈)] and Cs_{2.12}Na_{3.88}[U₂(SiS₄)₂(Si₂S₇)] can be obtained from CsI and CsI/NaI eutectic fluxes by reacting US₂, SiS₂, and Na₂S. The reaction yielded phase pure Cs₂Na₄[U₂(SiS₄)₂(Si₂S₈)], which exhibits paramagnetic properties as revealed by magnetic susceptibility measurements.

Oxychalcogenides

The ABI fluxes have also been employed to synthesize a variety of oxychalcogenide compounds. These are predominately oxyselenides ^{94–103}, but also include oxysulfides ^{104–107} and oxytellurides ¹⁰⁸. In many cases, the ABI flux is utilized as a recrystallizing agent. For example, single crystals of Ln_{3.67}Ti₂O₃Se₆ (Ln = Ce, Nd, Sm) were grown by mixing a powdered sample of the material, synthesized from stoichiometric quantities of Ln, TiO₂, Ti, and Se, with KBr in a fused silica tube. The reaction was heated to 950 °C for 96 h before being slow cooled to room temperature. ¹⁰⁰ In other cases, the materials are synthesized via the traditional flux method, where a combination of metal oxides and metal chalcogenides and/or elemental species, are combined with an ABI flux in an evacuated fused silica tube. La₅Cu₆O₄S₇ was grown in this way from a mixture of La₂S₃, CuO, and KI flux heated to 900 °C for 4 d and slow cooled to 300 °C at a rate of 3 °C/h. ¹⁰⁷ Similarly, La₆Ti₃O₅Se₉ was grown from a mixture of La, Ti, TiO₂, Se, and KI flux heated to 950 °C for 100 h and slow cooled to 700 °C at a rate of 3 °C/h. ¹⁰¹

In most cases, the oxychalcogenide material is formed by adding a limited, typically stoichiometric, amount of oxygen, in the form of a metal oxide precursor, into the evacuated fused silica tube. However, in the case of Ln₄S₃Si₂O₇, the oxygen was obtained from the reaction attacking the fused silica tube. These reactions utilized a KBr flux, as opposed to the alkali iodides that are used for the synthesis of most of the other oxychalcogenide systems, which is the likely cause of the fused silica etching. In a few other cases, an overstoichiometry of oxygen is

used in combination with boron metal as an oxygen getter. Fox example, BaGeOSe₂ was synthesized from a mixture of Ba, GeO₂, Se, B and KI flux. In this reaction, the excess oxygen associated with the GeO₂ is captured by the boron metal to form B₂O₃ as a side product.¹⁰²

The synthesized oxychalcogenides have been explored for two primary purposes. Due to the different size and electronegativity of oxygen versus chalcogenides, cationic oxychalcogenide polyhedra possess a larger polarity than their pure oxide counterparts. This can lead to increased second-harmonic generation when the oxychalcogenide crystallizes in a non-centrosymmetric space group. This is evident in non-centrosymmetric BaGeOSe₂, whose GeO₂Se₂ and BaOSe₆ polyhedra have dipole moments with magnitude 11.25 and 20.47, respectively. These are considerably greater than the moments of 4.65 and 4.70 for the respective pure oxide polyhedra and result in BaGeOSe₂ having a similar strength SHG response as AgGaS₂, a commercially used NLO crystal. A second interest in the oxychalcogenides arose from the discovery of high temperature superconductivity in the iron arsenides. As a result, considerable attention has been paid to structurally related rare-earth transition metal oxychalcogenides, for example, RE₂FeSe₂O₂ (RE = La, Ce). Description of the response and the structurally related rare-earth transition metal oxychalcogenides, for example, RE₂FeSe₂O₂ (RE = La, Ce).

Pnictides

Ternaries. The use of ABI fluxes has also resulted in a number of pnictide phases exhibiting unique structural features, further demonstrating the versatility of the alkali bromide and iodide flux systems. As an example, Lissner and Schleid employed a CsBr flux in reactions of lanthanide metal powders, sulfur, cesium azide, and lanthanide tribromides at 900°C to obtain single crystals of Ln₄N₂S₃ (Ln = La-Nd). ^{109, 110} It was noted that the four structures, which are isotypic to one another, exhibit an elongated Ln-S bond and an increase in the Ln(2) site coordination number from 6 to 6+1 along the series from La to Ce, an observation which diverges from expectations based on the lanthanide contraction. The authors later used similar methods to obtain the Ln₃NS₃ (Ln = La-Nd, Sm, Gd-Dy) series from a NaBr flux. ¹¹¹ Schurz *et al.* obtained the first gadolinium nitride selenides, Gd₃NSe₃ and Gd₂₃N₅Se₂₇, by replacing sulfur with selenium and using gadolinium triiodide with a CsI flux ¹¹². A distinctive feature in the structure of Gd₂₃N₅Se₂₇ is the presence of gadolinium cations with a coordination number of 5, significantly lower in coordination than what is typically observed in lanthanide solid-state structures (Figure 7), which

was attributed to the short coordinating anion bond distances of 2.20 Å for Gd(4)-N(1) and 2.77 Å for Gd(4)-Se(27) (Figure X).

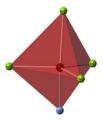


Figure 7. The unusually low five-fold coordination of Gd(4) in Gd₂₃N₅Se₂₇.

In an effort to prepare new low-dimensional materials for semiconductor applications, Na₂BP₂, a novel boron phosphide containing one-dimensional B-P chains was prepared. ¹⁸ To avoid formation of inert and thermodynamically-favored phases, Woo *et al.* utilized mild reaction temperatures and oxidative elimination to prepare single crystals of the metastable Na₂BP₂ phase from a mixture of Na₃BP₂ and CuI in a CsI-NaI eutectic that was heated to 500 °C. The authors suggested that this method may also offer a route to multidimensional materials by increasing the degree of oxidation. Using similar methods, Aydemir *et al.* serendipitously obtained Eu₃[B₃N₆], the first entirely europium(III) nitridoborate. ¹¹³ This phase was initially prepared from a NaBr flux and formed as a minor phase due to an EuBr₃ impurity in the starting materials; it was surmised that the decomposition of EuBr₃ into EuBr₂ and Br₂ resulted in the oxidation step which yielded the product. This hypothesis was confirmed by heating a mixture of a divalent europium precursor Eu₃[BN₂]₂ and Br₂ to 800 °C, yielding a mixture of Eu₃[B₃N₆] and EuBr₂. ¹¹³

Quaternaries. As opposed to the ternary pnictides, there have been only a few reports on the use of ABI fluxes to prepare quaternary pnictide phases. While combinations of lanthanide metal powder, sulfur or selenium, cesium azide, and lanthanum tribromides resulted in several ternary phases ($Ln_4N_2S_3$ (Ln = La-Nd), Gd_3NSe_3 , and $Gd_{23}N_5Se_{27}$), replacement of cesium azide with sodium azide resulted in the quaternary phase Nd_3N_2SeBr , ¹¹⁴ an outcome that emphasizes the importance in the choice of starting materials.

For photoelectrochemical water splitting applications, particles of SrNbO₂N were precalcined and heated in a variety of alkali halide fluxes; it was determined that SrNbO₂N particles flux-treated in NaI yielded the highest photocurrent density of 1.5 mA cm⁻² at 1.23 V_{RHE} under AM 1.5G irradiation. In the search for potential superconductors, LnFeAsO (Ln = La-Nd, Sm, Gd-Tb) has been studied, and was prepared by Nitsche *et al.* from a mixture of FeO, As, and

lanthanide metal in a NaI-KI flux at 1050 °C. 116 Similar methods were later used to produce large single crystals of LaFeAsO from a KI flux, which were isolated as plates having an edge length of up to 1 mm. 117

Salt-inclusion materials

Salt-inclusion materials (SIMs) represent a unique class of hierarchical materials that typically exhibit porous and covalent frameworks with interpenetrating ionic salt lattices. As functional materials, SIMs have wide-ranging applications as waste storage and ion exchange materials to optical materials. The zur Loye group has focused on synthesizing novel uranium-containing SIMs via alkali halide fluxes and while the majority of these have been prepared from ACl-AF eutectics, some success was achieved with the use of ABI fluxes. A novel intergrowth uranyl silicate, K8(K5F)U6Si8O40, was grown from a KF-KBr flux¹¹⁸ and, unlike many other uranyl compounds, K8(K5F)U6Si8O40 was found to exhibit intense luminescence behavior possibly attributable to the salt-inclusion. Similarly, a KF-KBr flux was used to prepare [KK6Br0.6F0.4][(UO2)3(Ge2O7)2] ¹¹⁹ in a study to explore the adaptability of the uranyl germanate SIM framework. This [(UO2)3(Ge2O7)2] framework was found to successfully accommodate twelve different salt-inclusions that were incorporated based on the selected flux used in the synthesis.

In addition to uranium-containing SIMs, ABI fluxes have demonstrated moderate success in stabilizing non-uranium SIMs as well. For example, the pentanary selenide (K₃I)[InB₁₂(InSe₄)₃] was synthesized from a KI flux.¹²⁰ The crystal structure of (K₃I)[InB₁₂(InSe₄)₃] is noncentrosymmetric and was found to be SHG active (Figure 8), exhibiting a higher SHG intensity than the isostructural (K₃I)[SmB₁₂(GaS₄)₃], which the authors suggested was on account of the larger dipole moment of the InSe₄ unit relative to GaS₄.

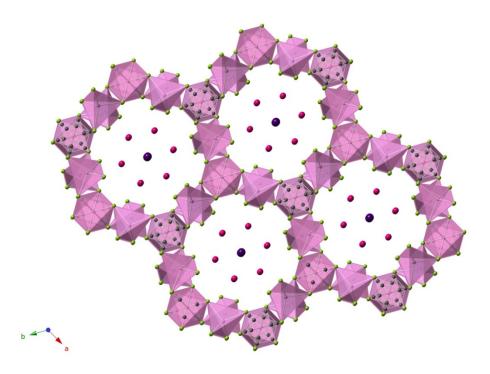


Figure 8. A view on the structure of $(K_3I)[InB_{12}(InSe_4)_3]$ salt-inclusion compound, which was obtained using KI flux. ¹²⁰

Nanomaterials

While flux crystal growth is typically used for the growth of single-crystal X-ray diffraction or larger sized single crystals (i.e. > 50 µm), ABI fluxes have also been used successfully in the preparation of nanostructure materials. For example, upon co-precipitating precursor FeCo particles, Kishimoto *et al.* facilitated particle growth by heating at 850°C in a KBr flux. For applications in photocatalysis, silver-loaded sodium titanates were prepared by traditional solid-state and flux methods, and while several ABI fluxes were evaluated including NaBr and NaI, it was determined that the Ag/Na₂Ti₆O₁₃ prepared from a NaCl flux resulted in the highest CO formation rate and the highest selectivity to CO. Locate Co. Locate

For applications in photoelectrochemical water splitting, Kodera *et al.* also found that the choice of flux and reaction conditions strongly affected the morphology of SrNbO₂N particles: ¹¹⁵ for example, the use of a NaBr flux resulted in column-like morphologies, while plate

morphologies resulted from KBr flux, and large block-like morphologies were resultant from NaI flux (Figure 9). The best photocurrent density of 1.5 mA cm⁻² at 1.23 V_{RHE} under AM 1.5G irradiation was achieved using a NaI flux with pre-calcination. Similarly, in their search for efficient light harvesting and charge transport materials Shi *et al.* determined that a KI flux could be used to prepare Ta₃N₅ nanorod arrays that were highly oriented along the [100] direction, where the size of the nanorods was controlled by the amount of flux present in the reaction. ¹²⁴

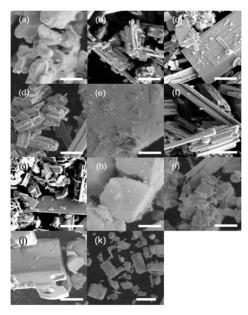


Figure 9. SEM images of oxide precursors produced (a) without flux, and with (b) NaCl, (c) KCl, (d) RbCl, (e) SrCl₂, (f) NaBr, (g) KBr, (h) NaI, (i) KI, (j) CsI, and (k) SrCl₂ fluxes. The scale bars in (a)-(j) are 2 μm, and that in (k) is 20 μm. Reproduced from Kodera, M.; Urabe, H.; Katayama, M.; Hisatomi, T.; Minegishi, T.; Domen, K., Effects of flux synthesis on SrNbO₂N particles for photoelectrochemical water splitting, J. Mater. Chem. A 2016, 4, 7658-7664. ¹¹⁵ under the Creative Commons CCBY-NC license – published by the Royal Society of Chemistry.

Conclusion

The ABI fluxes offer a convenient tool that provides a reaction and crystallization medium for different classes of inorganic compounds, mostly chalcogenides. They can be used in a very broad temperature range, from ~207 to ~1300 °C, by selecting pure salts or their eutectics using phase diagram databases, such as FactSage. ^{21–23} Both the selection of flux and the temperature profile can significantly affect the size and the shape of the resulting crystals, and often the reaction conditions have to be thoroughly optimized to achieve crystals of XRD quality. The ABI fluxes are not very reactive toward common reaction vessel materials, such as silica and alumina, which enables their broad use with different types of crucibles. ABI fluxes can be easily separated from

the reaction products using water, methanol, DMF, and other polar solvents. Most commonly, the elements and binaries are used as starting materials for ABI flux crystal growth; however, several new approaches coupled with the use of ABI fluxes have been developed recently. One of them, a reaction of an oxide with elemental boron and sulfur, shows a good promise for the synthesis of new chalcogenides as it allows using available oxide precursors and binds oxygen in the system by the excess of boron, which can result in purer products, especially for the elements that are known for binding oxygen, such as uranium and lanthanides.

As ABI fluxes provide a versatile platform for the synthesis of new compounds and different morphologies (crystals or nanoparticles), they will continue to be used for the design of new materials to meet the demands of modern technology. Alkali halide fluxes have been proven useful for the crystal growth of quantum spin liquid candidates, ¹²⁵ and ABI fluxes can serve as a facile route towards new magnetic and optical materials containing soft anions, such as chalcogenides. Further control over the properties of the new materials can be achieved by using ABI fluxes for design of particle size and shape, to create novel classes of nanomaterials. Therefore, the ABI flux has been established as a method of synthesis, and the future research will focus on using ABI fluxes for the synthesis of new classes of materials.

Funding

Financial support for this work was provided by the National Science Foundation under DMR-1806279 and is gratefully acknowledged. C. Juillerat is additionally supported by an NSF IGERT Graduate Fellowship under grant number 1250052.

References:

- (1) Kanatzidis, M. G.; Sutorik, A. C., The application of polychalcogenide salts to the exploratory synthesis of solid state multinary chalcogenides at intermediate temperatures, 1995, *Progress in Inorganic Chemistry, Volume 43*, 151-265.
- (2) Pace, K. A.; Klepov, V. V.; Morrison, G.; zur Loye, H.-C., Moderate supercritical synthesis as a facile route to mixed-valent uranium(iv,v) and (v,vi) silicates, *Chem. Commun.* **2018**,
- (3) Juillerat, C. A.; Klepov, V. V.; Morrison, G.; Pace, K. A.; zur Loye, H.-C., Flux Crystal Growth: A Versatile Technique to Reveal the Crystal Chemistry of Complex Uranium Oxides, *Dalton Trans.* **2019**, *48*, 3162-3181.
- (4) Bugaris, D. E.; zur Loye, H.-C., Materials discovery by flux crystal growth: Quartenary and higher oxides, *Angew. Chem. Int. Ed.* **2012**, *51*, 3780-3811.
- (5) Liu, X.; Fechler, N.; Antonietti, M., Salt melt synthesis of ceramics, semiconductors and carbon nanostructures, *Chem. Soc. Rev.* **2013**, *42*, 8237-8265.

- (6) Kanatzidis, M. G., Discovery-synthesis, design, and prediction of chalcogenide phases, *Inorg. Chem.* **2017**, *56*, 3158-3173.
- (7) Kanatzidis, M. G.; Pöttgen, R.; Jeitschko, W., The metal flux: a preparative tool for the exploration of intermetallic compounds, *Angew. Chem.* **2005**, *44*, 6996-7023.
- (8) Bugaris, D. E.; Ibers, J. A., Syntheses and characterization of some solid-state actinide (Th, U, Np) compounds, *Dalton Trans.* **2010**, *39*, 5925-6128.
- (9) Haynes, A. S.; Stoumpos, C. C.; Chen, H.; Chica, D.; Kanatzidis, M. G., Panoramic synthesis as an effective materials discovery tool: the system Cs/Sn/P/Se as a test case, *J. Am. Chem. Soc.* **2017**, *139*, 10814-10821.
- (10) Zeng, H. Y.; Zheng, F. K.; Guo, G. C.; Huang, J. S., Syntheses and single-crystal structures of La₃AgSnS₇, Ln₃M_xMS₇ (Ln= La, Ho, Er; M= Ge, Sn; $1/4 \le x \le 1/2$), *J. Alloys Compd.* **2008**, 458, 123-129.
- (11) Cortese, A. J.; Wilkins, B.; Smith, M. D.; Morrison, G.; zur Loye, H.-C., Single crystal growth and characterization of the first reduced lanthanum molybdenum oxychloride, La₂₀Mo₁₂O₆₃Cl₄, with an unusual trigonal prismatic MoO₆ unit, *Solid State Sciences* **2015**, 48, 133-140.
- (12) Read, C. M.; Smith, M. D.; zur Loye, H.-C., Synthesis, Crystal Structure, and Optical Properties of a New Complex Uranium Oxychloride, KUO₃Cl, *J. Chem. Cryst.* **2015**, *45*, 440-444.
- (13) Ruck, M.; Schmidt, P., Synthesen und Kristallstrukturen der homöotypen Selenitbromide Bi₈(SeO₃)₉Br₆ und CsSm₂₁(SeO₃)₂₄Br₁₆, Z. Anorg. Allg. Chem. **2003**, 629, 2133-2143.
- (14) Yahia, H. B.; Rodewalk, U. C.; Pöttgen, R., Crystal Structure of La₃OBr[AsO₃]₂, Z. *Naturforsch.* **2010**, *65b*, 1289-1292.
- (15) Wells, D. M.; Chan, G. H.; Ellis, D. E.; Ibers, J. A., UTa₂O(S₂)₃Cl₆: A ribbon structure containing a heterobimetallic 5d-5f M₃ cluster, *J. Solid State Chem.* **2010**, *183*, 285-290.
- (16) Klepov, V. V.; Breton, L. S.; Pace, K. A.; Kocevski, V.; Besmann, T. M.; zur Loye, H.-C., Size-Driven Stability of Lanthanide Thiophosphates Grown from an Iodide Flux, *Inorg. Chem.* **2019**, *58*, 6565-6573.
- (17) Guo, S. P.; Guo, G. C.; Wang, M. S.; Zou, J. P.; Xu, G.; Wang, G.-J.; Lonh, X.-F., A Series of New Infrared NLO Semiconductors, ZnY₆Si₂S₁₄, Al_xDy₃Si_yAl_{1-y}S₇, and Al_{0.33}Sm₃SiS₇, *Inorg. Chem.* **2009**, *48*, 7059-7065.
- (18) Woo, K. E.; Wang, J.; Mark, J.; Kovnir, K., Directing boron-phosphorus bonds in crystalline solid: oxidative polymerization of P= B= P monomers into 1D chains, *J. Am. Chem. Soc.* **2019**, *141*, 13017-13021.
- (19) Lipp, C.; Burns, P. C.; Schleid, T., Pr₅F[SiO₄₂[SeO₃]₃: Another Complex Fluoride Oxosilicate Oxoselenate(IV), Z. Anorg. Allg. Chem. **2012**, 638, 779-784.
- (20) Morrison, G.; Smith, M. D.; zur Loye, H.-C., Understanding the Formation of Salt-Inclusion Phases: An Enhanced Flux Growth Method for the Targeted Synthesis of Salt-Inclusion Cesium Halide Uranyl Silicates, *J. Am. Chem. Soc.* **2016**, *138*, 7121-7129.
- (21) Bale, C. W.; Chartrand, P.; Degterov, S. A.; Eriksson, G.; Hack, K.; Mahfoud, R. B.; Melançon, J.; Pelton, A. D.; Petersen, S., FactSafe thermochemical software and databases, *Calphad* **2002**, *26*, 189-228.
- (22) Bale, C. W.; Bélisle, E.; Chartrand, P.; Decterov, S. A.; Eriksson, G.; Hack, K.; Jung, I.-H.; Kang, Y.-B.; Melançon, J.; Pelton, A. D.; Robelin, C.; Petersen, S., FactSage thermochemical software and databases recent developments, *Calphad* **2009**, *33*, 295-311.

- (23) Bale, C. W.; Bélisle, E.; Chartrand, P.; Decterov, S. A.; Eriksson, G.; Gheribi, A. E.; Hack, K.; Jung, I.-H.; Kang, Y.-B.; Melançon, J.; Pelton, A. D.; Petersen, S.; Robelin, C.; Sangster, J.; Spencer, P.; Van Ende, M.-A., FactSage thermochemical software and databases, 2010–2016, *Calphad* **2016**, *54*, 35-53.
- (24) Winiarski, M. J.; Tran, T. T.; Chamorro, J. R.; McQueen, T. M., (CsX)Cu₅O₂(PO₄)₂ (X = Cl, Br, I): A Family of Cu²⁺ S = 1/2 Compounds with Capped Kagomé Networks COmposed of OCu₄ Units, *Inorg. Chem.* **2019**, *58*, 4328-4336.
- (25) Gouëllo, M.; Hokkinen, J.; Kärkelä, T.; Auvinen, A., A Scoping Study of the Chemical Behavior of Cesium Iodide in the Presence of Boron in the Condensed Phase (650°C and 400°C) Under Primary Circuit Conditions, *Nucl. Technol.* **2018**, *203*, 66-84.
- (26) Lipp, C.; Schleid, T., Er₃F[SiO₄][SeO₃]₂: An ErF₃-Derivative with Two Different Kinds of Complex Oxoanions, *Z. Anorg. Allg. Chem.* **2008**, *634*, 1025-1029.
- (27) Lipp, C.; Dinnebier, R. E.; Schleid, T., LuF[SeO₃]: the structural chameleon of lanthanoid fluoride oxoselenates(IV)., *Inorg. Chem.* **2013**, *52*, 10788-10794.
- (28) Lipp, C.; Burns, P. C.; Schleid, T., Pr₅F[SiO₄]₂[SeO₃]₃: Another Complex Fluoride Oxosilicate Oxoselenate(IV), Z. Anorg. Allg. Chem. **2012**, 638, 779-784.
- (29) Chou, S.-C.; Greiner, S.; Magdysyuk, O. V.; Dinnebier, R. E.; Schleid, T., Theoretical and Experimental Analysis of Structural Phase Transitions for ScF[SeO₃] and YF[SeO₃], *Z. Anorg. Allg. Chem.* **2014**, *640*, 3203-3211.
- (30) Greiner, S.; Chou, S.-C.; Schleid, T., Two anionically derivatized scandium oxoselenates(IV): ScF[SeO₃] and Sc₂O₂[SeO₃], *J. Solid State Chem.* **2017**, *246*, 160-166.
- (31) Lipp, C.; Schleid, T., Ein neues Selten-Erd-Metall(III)-Fluorid-Oxoselenat(IV): YF[SeO₃], Z. Anorg. Allg. Chem. **2008**, 634, 657-661.
- (32) Lipp, C.; Schleid, T., HoF[SeO₃] und Ho₃F[SeO₃]₄: Zwei fluorid-derivatisierte Oxoselenate(IV) des Holmiums, Z. Anorg. Allg. Chem. **2008**, 634, 1662-1668.
- (33) Lipp, C.; Schleid, T., LuF[SeO₃] und LuCl[SeO₃]: Zweinicht-isotype Halogenid-Oxoselenate(IV) des Lutetiums, *Z. Anorg. Allg. Chem.* **2007**, *633*, 1429-1434.
- (34) Wickleder, C.; Hartenbach, I.; Lauxmann, P.; Schleid, T., Eu₅F[SiO₄]₃ und Yb₅S[SiO₄]₃: Gemischtvalente Lanthanoid-Silicate mit Apatit-StrukturProfessor Welf Bronger zum 70. Geburtstag gewidmet, *Z. Anorg. Allg. Chem.* **2002**, *628*, 1602.
- (35) Lipp, C.; Schleid, T., The Rare-Earth Metal(III) Fluoride Oxoselenates(IV) MF[SeO₃] (M = Y, Ho–Lu) with YF[SeO₃]-type Structure, *Z. Naturforsch* **2009**, *64B*, 375-382.
- (36) Liu, C.; Liu, Y.; Lyu, Y.; Lyu, C., Morphology and photoluminescence properties of NaNd(MoO4)2 synthesized by a molten salt method, *J. Mater. Sci.: Mater. Electron.* **2016**, 27, 5735-5740.
- (37) Wu, T.; Liu, Y.; Lu, Y.; Wei, L.; Gao, H.; Chen, H., Morphology-controlled synthesis, characterization, and luminescence properties of KEu(MoO₄)₂ microcrystals, *CrystEngComm* **2013**, *15*, 2761-2768.
- (38) Yamada, T.; Zettsu, N.; Kim, H.-m.; Hagano, Y.; Handa, N.; Yubuta, K.; Teshima, K., One-Dimensional Growth of Li₂NiPO₄F Single Crystals from Intermediate LiNiPO₄ Crystal Surface Using KCl–KI Fluxes, *Cryst. Growth Des.* **2018**, *18*, 6777-6785.
- (39) Hamilton, A. M.; O'Donnell, S.; Zoellner, B.; Sullivan, I.; Maggard, P. A., Flux-mediated synthesis and photocatalytic activity of NaNbO₃ particles, *J. Am. Ceram. Soc.* **2020**, *103*, 454-464.

- (40) Zhang, P.; Chen, X.; Zhang, Z.; Fei, M.; Chen, L., Synthesis and photoluminescence of the blue phosphor Sr₃MgSi₂O₈:Eu²⁺ optimized with the Taguchi method for application in near ultraviolet excitable white light-emitting diodes, *J. Lumin.* **2016**, *169*, 733-738.
- (41) Shivakumara, C.; Subbanna, G. N.; Lalla, N. P.; Hegde, M. S., Na substitution for La- and Mn-sites in LaMnO₃ from alkali halide fluxes: low temperature synthesis, structure and properties, *Mater. Res. Bull.* **2004**, *39*, 71-81.
- (42) Shivakumara, C.; Hegde, M. S.; Subbanna, G. N., Low temperature synthesis of ferromagnetic (LaK)MnO₃ from KCl, KBr and KI fluxes, *Solid State Sci.* **2001**, *3*, 43-48.
- (43) Yanagida, H.; Atumi, M., The Effectiveness of Alkali Halide Media for the Process of MgFe₂O₄ formation, *J. Ceram. Assoc. Jpn.* **1967**, *75*, 349-352.
- (44) Liu, G.; Greedan, J. E., Magnetic Properties of Fresnoite-Type Vanadium Oxides: A₂V₃O₈ (A = K, Rb, NH₄), *J. Solid State Chem.* **1995**, *114*, 499-505.
- (45) Sanjaya Ranmohotti, K. G.; Mo, X.; Smith, M. K.; Hwu, S.-J., Synthesis, structure, and magnetic properties of Cs_{2-x}Rb_xCu₃P₄O₁₄ (0.0 ≤ x ≤ 0.8): a new series of copper(II) phosphates containing periodic arrays of staggered square-planar CuO4 trimers., *Inorg. Chem.* **2006**, *45*, 3665-3670.
- (46) Ulutagay-Kartin, M.; Hwu, S.-J.; Clayhold, J. A., Nanostructured magnetic cuprate cluster: synthesis, structure, UV-Vis spectroscopy, and magnetic properties of a new copper(II) arsenate NaCuAsO₄ containing discrete [Cu₄O₁₆]₂⁴ clusters., *Inorg. Chem.* **2003**, *42*, 2405-2409.
- (47) Weil, M., Crystal structures of the triple perovskites Ba₂K₂Te₂O₉, Ba₂KNaTe₂O₉, and redetermination of the double perovskite Ba₂CaTeO₆, *Acta Cryst.* **2018**, *E74*, 1006-1009.
- (48) Shivakumara, C.; Hegde, M. S., Low temperature synthesis of layered Na_xCoO₂ and K_xCoO₂ from NaOH/KOH fluxes and their ion exchange properties, *Journal of Chemical Sciences* **2003**, *115*, 447-457.
- (49) Yagoubi, S.; Renard, C.; Abraham, F.; Obbade, S., Molten salt flux synthesis and crystal structure of a new open-framework uranyl phosphate Cs₃(UO₂)₂(PO₄)O₂: Spectroscopic characterization and cationic mobility studies, *J. Solid State Chem.* **2013**, 200, 13-21.
- (50) Shishido, T., Growth and Characterization of Bi₂(Sr_{1-x}Ca_x)₃Cu₂O_y Single Crystals Extracted from KBr Flux, *Jpn. J. Appl. Phys.* **1990**, *29*, 2413-2414.
- (51) Habermehl, K.; Mudring, A.-V.; Meyer, G., The Last of the Five: the Elusive "Tantalum(III) Bromide", a Perovskite-Related Salt, [Ta₆Br₁₂]Br₃[TaBr₆]_{0.86}, Eur. J. Inorg. Chem. **2010**, 2010, 4075-4078.
- (52) Beekhuizen, J.; Mudring, A.-V.; Meyer, G., Linear Trimeric Hafnium Clusters in Hf_{0.86(1)}I₃, *Crystals* **2011**, *1*, 40-46.
- (53) Riggs, S. C.; Shapiro, M. C.; Corredor, F.; Geballe, T. H.; Fisher, I. R.; McCandless, G. T.; Chan, J. Y., Single crystal growth by self-flux method of the mixed valence gold halides Cs₂[Au^{IX}₂][Au^{III}₄X₄] (X=Br,I), *J. Cryst. Growth* **2012**, *355*, 13-16.
- (54) Steinwand, S. J.; Corbett, J. D., Oligomeric Rare-Earth-Metal Halide Clusters. Three Structures Built of (Y(6Z4)Br₃₆ Units (Z = Ru, Ir)., *Inorg. Chem.* **1996**, *35*, 7056-7067.
- (55) Frühmann, B.; Kubel, F.; Hagemann, H.; Bill, H., Synthesis and Structure of the new Fluoride Bromide Ba_{6.668(2)}Ca_{0.332(2)}F₁₂Br₂ and Solid Solutions with Composition Ba_{7-x}Ca_xF₁₂(Cl_yBr_{1-y})₂ with $x = \sim 0.5$, 0 < y < 1, Z. Anorg. Allg. Chem. **2004**, 630, 1484-1488.
- (56) Liao, W.; Hu, C.; Kremer, R. K.; Dronskowski, R., Formation of Complex Three- and One-Dimensional Interpenetrating Networks within Carbodiimide Chemistry: NCN -

- Coordinated Rare-Earth-Metal Tetrahedra and Condensed Alkali-Metal Iodide Octahedra in Two Novel Lithium Europium Carbodiimide Iodides, LiEu₂(NCN)I₃ and LiEu₄(NCN)₃I₃, *Inorg. Chem.* **2004**, *43*, 5884-5890.
- (57) Liao, W.; von Appen, J.; Dronskowski, R., LiSr₂(NCN)I₃: the first empty tetrahedral strontium(II) entity coordinated by carbodiimide units but without strontium–strontium bonding, *Chem. Commun.* **2004**, *20*, 2302-2303.
- (58) Lissner, F.; Schleid, T., Nitridsulfidhalogenide der leichten Lanthanide vom Typ M₆N₃S₄X (M = La-Nd; X= Cl, Br) mit ausgeordneten Sulfid- und Halogenid-Lagen, *Z. Naturforsch.* **2002**, *57b*, 1079-1084.
- (59) Daub, K.; Meyer, G., Isolated and Edge-Connected Tetramers {(C₂)₂O₂Dy₁₄} in the Crystal Structures of {(C₂)₂O₂Dy₁₄}I₂₄ and {(C₂)₂O₂Dy₁₂}I₁₈, Z. Anorg. Allg. Chem. **2010**, 636, 1716-1719.
- (60) Zhang, M.-J.; Jiang, X.-M.; Zhou, L.-J.; Guo, G.-C., Two phases of Ga₂S₃: promising infrared second-order nonlinear optical materials with very high laser induced damage thresholds, *J. Mater. Chem. C* **2013**, *1*, 4754.
- (61) Kawai, H.; Abe, T.; Hoshina, T., Effects of Fluxes on Particle Growth of ZnS Phosphor, *Jpn. J. Appl. Phys.* **1981**, *20*, 313-320.
- (62) Wang, Y.; Wu, J.; Tang, Y.; Lü, X.; Yang, C.; Qin, M.; Huang, F.; Li, X.; Zhang, X., Phase-controlled synthesis of cobalt sulfides for lithium ion batteries., *ACS Appl. Mater. Interfaces* **2012**, *4*, 4246-4250.
- (63) Cao, L.; Lv, Y.-Y.; Chen, S.-S.; Li, X.; Zhou, J.; Yao, S.-H.; Chen, Y. B.; Lu, M.; Chen, Y.-F., Crystal growth and magneto-transport behavior of PdS_{1-δ}, *J. Cryst. Growth* **2018**, 487, 116-119.
- (64) Vasilyeva, I. G.; Belaya, S. V., Sulfur Nonstoichiometry of PrS₂: A Series of New Sulfur-Deficient Phases, *J. Solid State Chem.* **1999**, *146*, 211-216.
- (65) Ijjaali, I.; Ibers, J. A., Two new binary lanthanide polytellurides: Syntheses and crystal structures of CeTe_{1.90} and SmTe_{1.80}, *J. Solid State Chem.* **2006**, *179*, 3456-3460.
- (66) Timmo, K.; Kauk-Kuusik, M.; Pilvet, M.; Mikli, V.; Kärber, E.; Raadik, T.; Leinemann, I.; Altosaar, M.; Raudoja, J., Comparative study of SnS recrystallization in molten CdI₂, SnCl₂ and KI: Comparative study of SnS recrystallization in molten CdI, *Phys. Status Solidi C* **2016**, *13*, 8-12.
- (67) Zeng, H.-Y.; Zhang, M.-J.; Liu, B.-W.; Ye, N.; Zhao, Z.-Y.; Zheng, F.-K.; Guo, G.-C.; Huang, J.-S., NaIn₃S₅, a new compound from the CaS–In₂S₃/NaBr system, *J. Alloys Compd.* **2015**, *624*, 279-283.
- (68) Reynolds, T. K.; Kelley, R. F.; DiSalvo, F. J., Electronic transport and magnetic properties of a new nickel antimonide telluride, Ni₂SbTe₂, *J. Alloys Compd.* **2004**, *366*, 136-144.
- (69) Babo, J.-M.; Schleid, T., Synthesis and Crystal Structure of the Rubidium Scandium Telluride RbSc₅Te₈, *Z. Anorg. Allg. Chem.* **2008**, *634*, 1463-1465.
- (70) Babo, J.-M.; Schleid, T., Two Alkali-Metal Yttrium Tellurides: Single Crystals of Trigonal KYTe₂ and Hexagonal RbYTe₂, *Z. Anorg. Allg. Chem.* **2009**, *635*, 1160-1162.
- (71) Prakash, J.; Mesbah, A.; Beard, J. C.; Malliakas, C. D.; Ibers, J. A., Syntheses, crystal structures, and resistivities of the two new ternary uranium selenides, Er₃USe₈ and Yb₃USe₈, *J. Solid State Chem.* **2016**, *233*, 90-94.
- (72) Huang, F. Q.; Ibers, J. A., Gd₃Cu₂Te₇ and U₂Cu_{0.78}Te₆: Two Examples of Linear Te Chains, *J. Solid State Chem.* **2001**, *159*, 186-190.

- (73) Strobel, S.; Lauxmann, P.; Schleid, T., Münzmetall-Lanthanid-Chalkogenide: I. Kupfer(I)-Lanthanid(III)-Sulfide der Zusammensetzung CuMS₂ (M = La Nd, Sm, Gd, Tb) im monoklinen A-Typ, *Z. Naturforsch.* **2005**, *60b*, 917-923.
- (74) Strobel, S.; Schleid, T., Münzmetall-Lanthanid-Chalkogenide: II. Kupfer(I)-Lanthanid(III) Sulfide der Zusammensetzung CuMS₂ (M = Dy Lu) im orthorhombischen B-Typ, *Z. Naturforsch.* **2007**, *62b*, 15-22.
- (75) Ijjaali, I.; Mitchell, K.; Ibers, J. A., Preparation and structure of the light rare-earth copper selenides LnCuSe₂ (Ln=La, Ce, Pr, Nd, Sm), *J. Solid State Chem.* **2004**, *177*, 760-764.
- (76) Deng, B.; Ellis, D. E.; Ibers, J. A., New layered rubidium rare-earth selenides: syntheses, structures, physical properties, and electronic structures for RbLnSe₂., *Inorg. Chem.* **2002**, *41*, 5716-5720.
- (77) Tougait, O.; Ibers, J. A., Ternary rare-earth selenides with the U₃ScS₆ structure type: synthesis, characterization, and some magnetic properties of Ln₃TSe₆ (Ln = Sm, Gd; T = In, Cr) and Tb₃CrSe₆., *Inorg. Chem.* **2000**, *39*, 1790-1794.
- (78) Gray, D. L.; Rodriguez, B. A.; Chan, G. H.; Van Duyne, R. P.; Ibers, J. A., Synthesis and characterization of Er₃SmQ₆ (Q=S, Se) and Er_{1.12}Sm_{0.88}Se₃, *J. Solid State Chem.* **2007**, *180*, 1527-1532.
- (79) Lin, H.; Li, Y.-Y.; Li, M.-Y.; Ma, Z.; Wu, L.-M.; Wu, X.-T.; Zhu, Q.-L., Centric-to-acentric structure transformation induced by a stereochemically active lone pair: a new insight for design of IR nonlinear optical materials, *J. Mater. Chem. C* **2019**, *7*, 4638-4643.
- (80) Kuo, S.-M.; Chang, Y.-M.; Chung, I.; Jang, J.-I.; Her, B.-H.; Yang, S.-H.; Ketterson, J. B.; Kanatzidis, M. G.; Hsu, K.-F., New Metal Chalcogenides Ba₄CuGa₅Q₁₂ (Q = S, Se) Displaying Strong Infrared Nonlinear Optical Response, *Chem. Mater.* **2013**, *25*, 2427-2433.
- (81) Li, Y.-Y.; Wang, H.; Sun, B.-W.; Ruan, Q.-Q.; Geng, Y.-L.; Liu, P.-F.; Wang, L.; Wu, L.-M., Ba₁₀Zn₇M₆Q₂₆: Two New Mid-infrared Nonlinear Optical Crystals with T2 Supertetrahedron 3D Framework, *Cryst. Growth Des.* **2018**, *19*, 1190-1197.
- (82) Bezuidenhout, D. I.; van der Westhuizen, B.; Swarts, P. J.; Chatturgoon, T.; Munro, O. Q.; Fernández, I.; Swarts, J. C., Redox behaviour of cymantrene Fischer carbene complexes in designing organometallic multi-tags., *Chem. Eur. J.* **2014**, *20*, 4974-4985.
- (83) Yao, J.; Deng, B.; Ellis, D. E.; Ibers, J. A., Syntheses, structures, physical properties, and electronic structures of KLn₂CuS₄ (Ln=Y, Nd, Sm, Tb, Ho) and K₂Ln₄Cu₄S₉ (Ln=Dy, Ho), *J. Solid State Chem.* **2003**, *176*, 5-12.
- (84) Strobel, S.; Schleid, T., Quaternary Strontium Copper(I) Lanthanoid(III) Selenides with Cerium and Praseodymium: SrCuCeSe₃ and SrCuPrSe₃, Unequal Brother and Sister, *Z. Naturforsch.* **2004**, *59b*, 985-991.
- (85) Yang, Y.; Ibers, J. A., Synthesis and Characterization of a Series of Quaternary Chalcogenides BaLnMQ3 (Ln=Rare Earth, M=Coinage Metal, Q=Se or Te), *J. Solid State Chem.* **1999**, *147*, 366-371.
- (86) Yang, Y.; Ibers, J. A., Syntheses and Structures of the New Quaternary Compounds Ba₄Nd₂Cd₃Se₁₀ and Ba₄Ln₂Cd₃S₁₀ (Ln=Sm, Gd, Tb), *J. Solid State Chem.* **2000**, *149*, 384-390.
- (87) Zeng, H. Y.; Mattausch, H.; Simon, A.; Zheng, F. K.; Dong, Z. C.; Guo, G. C.; Huang, J. S., KCaEr₂CuS₅: a new pentanary rare-earth layered chalcogenide without substitutional disorder., *Inorg. Chem.* **2006**, *45*, 7943-7946.

- (88) Dong, Y.; Kim, S.; Yun, H., A new thiophosphate, Rb_{0.38}Ag_{0.5}Nb₂PS₁₀., *Acta Cryst.* **2005**, *C61*, i25-i26.
- (89) Dong, Y.-K.; King, S.-R.; Yun, H.-S.; Lim, H.-J., Synthesis and Crystal Structure of a New Pentanary Thiophosphate, K_{0.5}Ag_{0.5}Nb₂PS₁₀, *Bull. Korean Chem. Soc.* **2005**, *26*, 309-311.
- (90) Komm, T.; Schleid, T., The first rubidium rare-earth(III) thiophosphates: Rb₃M₃[PS₄]₄ (M=Pr, Er), *J. Solid State Chem.* **2005**, *178*, 454-463.
- (91) Komm, T.; Schleid, T., The New Cesium Praseodymium Thiophosphate Cs₃Pr₅[PS₄]₆, Z. *Anorg. Allg. Chem.* **2004**, *630*, 712-716.
- (92) Klepov, V. V.; zur Loye, H.-C., Complex Topologies from Simple Building Blocks: Uranium(IV) Thiophosphates, *Inorg. Chem.* **2018**, *57*, 11175-11183.
- (93) Hartenbach, I.; Schleid, T., NaY₃S₃[SiS₄]: a sodium-containing yttrium sulfide thiosilicate with channel structure, *J. Solid State Chem.* **2003**, *171*, 382-386.
- (94) Peschke, S.; Nitsche, F.; Johrendt, D., Flux Synthesis, Modulated Crystal Structures, and Physical Properties of REMn_{0.5}SeO (= La, Ce), *Z. Anorg. Allg. Chem.* **2015**, *641*, 529-536.
- (95) Peschke, S.; Johrendt, D., Flux Synthesis, Crystal Structures, and Magnetism of the Series La_{2n+2}MnSe_{n+2}O_{2n+2} (n = 0–2), *Inorganics* **2017**, *5*, 9.
- (96) Peschke, S.; Gamperl, L.; Weippert, V.; Johrendt, D., Flux synthesis, crystal structures, and physical properties of new lanthanum vanadium oxyselenides., *Dalton Trans.* **2017**, *46*, 6230-6243.
- (97) Peschke, S.; Weippert, V.; Senyshyn, A.; Mühlbauer, M. J.; Janka, O.; Pöttgen, R.; Holenstein, S.; Luetkens, H.; Johrendt, D., Flux Synthesis, Crystal Structures, and Magnetic Ordering of the Rare-Earth Chromium(II) Oxyselenides RE₂CrSe₂O₂ (RE = LaNd), *Inorg. Chem.* **2017**, *56*, 2241-2247.
- (98) Peschke, S.; Johrendt, D., The modulated structures of $La_{2-x}Pr_xO_2MnSe_2$ ($0 \le x \le 1$) and $La_{2-x}Nd_xO_2MnSe_2$ ($0 \le x \le 0.6$), Zeitschrift für Kristallographie -Crystalline Materials **2016**, 231, 89-95.
- (99) Tougait, O.; Ibers, J. A., Gd₂OSe₂, Acta Cryst. **2000**, C56, 623-624.
- (100) Tougait, O.; Ibers, J. A., Synthesis and Characterization of Three New Rare-Earth Titanium Oxyselenides: Ln_{3.67}Ti₂O₃Se₆ (Ln = Ce, Nd, Sm), *Chem. Mater.* **2000**, *12*, 2653-2658.
- (101) Tougait, O.; Ibers, J. A., Syntheses and Crystal Structures of the Lanthanum Titanium Oxyselenides La₄Ti₂O₄Se₅ and La₆Ti₃O₅Se₉, *J. Solid State Chem.* **2001**, *157*, 289-295.
- (102) Liu, B.-W.; Jiang, X.-M.; Wang, G.-E.; Zeng, H.-Y.; Zhang, M.-J.; Li, S.-F.; Guo, W.-H.; Guo, G.-C., Oxychalcogenide BaGeOSe₂: Highly Distorted Mixed-Anion Building Units Leading to a Large Second-Harmonic Generation Response, *Chem. Mater.* **2015**, *27*, 8189-8192.
- (103) Nitsche, F.; Niklaus, R.; Johrendt, D., New Polymorphs of RE₂FeSe₂O₂ (RE = La, Ce), *Z. Anorg. Allg. Chem.* **2014**, *640*, 2897-2902.
- (104)Zeng, H.-Y.; Mao, J.-G.; Dong, Z.-C.; Guo, G.-C.; Huang, J.-S., Synthesis and Crystal Structure of Ho₄S₃Si₂O₇, *Chin. J. Struct. Chem* **2002**,
- (105)Zeng, H.-Y.; Mao, J.-G.; Huang, J.-S., Synthesis and crystal structure of La₄S₃Si₂O₇, *J. Alloys Compd.* **1999**, *291*, 89-93.
- (106)Chi, Y.; Guo, S.-P.; Kong, H.-J.; Xue, H.-G., Crystal and electronic structures, and optical and magnetic properties of novel rare-earth sulfide borates RE₃S₃BO₃ (RE = Sm, Gd), *New J. Chem.* **2016**, *40*, 6720-6727.

- (107) Huang, F. Q.; Brazis, P.; Kannewurf, C. R.; Ibers, J. A., Synthesis, Structure, Electrical Conductivity, and Band Structure of the Rare-Earth Copper Oxychalcogenide La₅Cu₆O₄S₇, *J. Solid State Chem.* **2000**, *155*, 366-371.
- (108) Liu, M. L.; Wu, L. B.; Huang, F. Q.; Chen, L. D.; Ibers, J. A., Syntheses, crystal and electronic structure, and some optical and transport properties of LnCuOTe (Ln=La, Ce, Nd), *J. Solid State Chem.* **2007**, *180*, 62-69.
- (109)Lissner, F.; Schleid, T., The A-Type Ln₄N₂S₃ Series: New Nitride Sulfides of the Light Lanthanoids (Ln = Ce–Nd), *Inorganics* **2017**, *5*, 2.
- (110)Lissner, F.; Schleid, T., La₄N₂S₃: Ein neues Nitridsulfid des Lanthans mit beispielloser Kristallstruktur, *Z. Anorg. Allg. Chem.* **2006**, *632*, 1167-1172.
- (111)Lissner, F.; Meyer, M.; Kremer, R. K.; Schleid, T., M₃NS₃ (M = La Nd, Sm, Gd Dy): Struktur und Magnetismus von 3:1:3-Typ-Nitridsulfiden dreiwertiger Lanthanide, *Z. Anorg. Allg. Chem.* **2006**, *632*, 1995-2002.
- (112) Schurz, C. M.; Talmon-Gros, P.; Lissner, F.; Schleid, T., The gadolinium nitride selenides Gd₃NSe₃ and Gd₂₃N₅Se₂₇: Three connectivity types of [NGd₄]⁹⁺ tetrahedra and fivefold coordinated Gd³⁺ cations, *Solid State Sci.* **2013**, *17*, 140-145.
- (113) Aydemir, U.; Kokal, I.; Prots, Y.; Förster, T.; Sichelschmidt, J.; Schappacher, F. M.; Pöttgen, R.; Ormeci, A.; Somer, M., A novel europium (III) nitridoborate Eu₃[B₃N₆]: Synthesis, crystal structure, magnetic properties, and Raman spectra, *J. Solid State Chem.* **2016**, *239*, 75-83.
- (114)Lissner, F.; Schleid, T., Nd₃N₂SeBr: Ein neues Nitridselenidbromid des Neodyms mit-Strängen aus hochkondensierten [NNd₄]⁹⁺ -Tetraedern, Z. Anorg. Allg. Chem. **2007**, 633, 1973-1978.
- (115)Kodera, M.; Urabe, H.; Katayama, M.; Hisatomi, T.; Minegishi, T.; Domen, K., Effects of flux synthesis on SrNbO₂N particles for photoelectrochemical water splitting, *J. Mater. Chem. A* **2016**, *4*, 7658-7664.
- (116) Nitsche, F.; Jesche, A.; Hieckmann, E.; Doert, T.; Ruck, M., Structural trends from a consistent set of single-crystal data of RFeAsO (R = La, Ce, Pr, Nd, Sm, Gd, and Tb), *Phys. Rev. B* **2010**, *82*, 134514.
- (117) Jesche, A.; Nitsche, F.; Probst, S.; Doert, T.; Müller, P.; Ruck, M., Anisotropic electrical resistivity of LaFeAsO: Evidence for electronic nematicity, *Phys. Rev. B* **2012**, *86*, 134511.
- (118) Morrison, G.; Tran, T. T.; Halasyamani, P. S.; zur Loye, H.-C., K₈(K₅F)U₆Si₈O₄₀: An Intergrowth Uranyl Silicate., *Inorg. Chem.* **2016**, *55*, 3215-3217.
- (119) Juillerat, C. A.; Moore, E. E.; Morrison, G.; Smith, M. D.; Besmann, T. M.; zur Loye, H.-C., Versatile Uranyl Germanate Framework Hosting Twelve Different Alkali Halide 1D Salt Inclusions, *Inorg. Chem.* **2018**, *57*, 11606-11615.
- (120)Guo, S. P.; Chi, Y.; Liu, B. W.; Guo, G. C., Synthesis, crystal structure and second-order nonlinear optical property of a novel pentanary selenide (K₃I)[InB₁₂(InSe₄)₃]., *Dalton Trans.* **2016**, *45*, 10459-10465.
- (121) Kishimoto, M.; Latiff, H.; Kita, E.; Yanagihara, H., Characterization of FeCo particles synthesized via co-precipitation, particle growth using flux treatment and reduction in hydrogen gas, *J. Magn. Magn. Mater.* **2017**, *432*, 404-409.
- (122)Zhu, X.; Anzai, A.; Yamamoto, A.; Yoshida, H., Silver-loaded sodium titanate photocatalysts for selective reduction of carbon dioxide to carbon monoxide with water, *Applied Catalysis B: Environmental* **2019**, *243*, 47-56.

- (123) Kong, X.; Lou, T.; Li, Y., Fe₇S₈ nanorods and nanosheets, *J. Alloys Compd.* **2005**, *390*, 236-239.
- (124) Shi, Z.; Xu, Z.; Feng, J.; Huang, H.; Qian, Q.; Yan, S.; Zou, Z., Molten salt-assisted -axis-oriented growth of Ta₃N₅ nanorod arrays with enhanced charge transport for efficient photoelectrochemical water oxidation, *CrystEngComm* **2018**, *20*, 5364-5369.
- (125) Ferreira, T.; Xing, J.; Sanjeewa, L. D.; Sefat, A. S., Frustrated Magnetism in Triangular Lattice TlYbS₂ Crystals Grown via Molten Flux, *Frontiers in Chemistry* **2020**, *8*, 127.

